



Fast Switching Diode

Features

- Silicon Epitaxial Planar Diodes
- · Low forward voltage drop
- · High forward current capability

Applications

High speed switch and general purpose use in computer and industrial applications



Case: MiniMELF Glass Case (SOD-80)

Weight: approx. 30 mg
Cathode Band Color: Black
Packaging Codes/Options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box GS08 / 2.5 k per 7" reel (8 mm tape), 12.5 k/box



Parts Table

Part	Type differentiation	Ordering code	Remarks
LL4150	V _{RRM} = 50 V	LL4150-GS18 or LL4150-GS08	Tape and Reel

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V_{RRM}	50	V
Reverse voltage		V _R	50	V
Peak forward surge current	t _p = 1 μs	I _{FSM}	4	Α
Forward current		l _F	600	mA
Average forward current	V _R = 0	I _{FAV}	300	mA
Power dissipation		P _V	500	mW

Thermal Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Junction ambient	on PC board 50 mm x 50 mm x 1.6 mm	R_{thJA}	500	K/W
Junction temperature		T _j	175	°C
Storage temperature range		T _{stg}	- 65 to + 175	°C

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Rev. 1.6, 06-Apr-04

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Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward voltage	I _F = 1 mA	V _F	0.54		0.62	V
	I _F = 10 mA	V _F	0.66		0.74	V
	I _F = 50 mA	V _F	0.76		0.86	V
	I _F = 100 mA	V _F	0.82		0.92	V
	I _F = 200 mA	V _F	0.87		1.0	V
Reverse current	V _R = 50 V	I _R			100	nA
	V _R = 50 V, T _j = 150 °C	I _R			100	μΑ
Diode capacitance	$V_R = 0$, $f = 1$ MHz, $V_{HF} = 50$ mV	C _D			2.5	pF
Reverse recovery time	$I_F = I_R = 10 \text{ to } 100 \text{ mA},$	t _{rr}			4	ns
	$i_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$					

Typical Characteristics (T_{amb} = 25 °C unless otherwise specified)

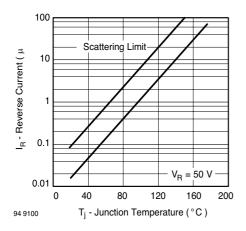


Fig. 1 Reverse Current vs. Junction Temperature

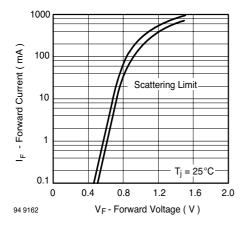
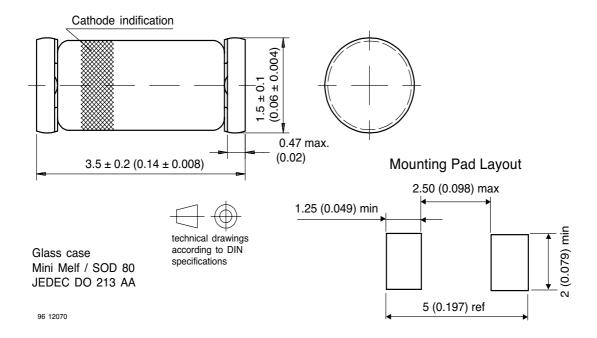


Fig. 2 Forward Current vs. Forward Voltage



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Package Dimensions in mm (Inches)



LL4150

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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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Document Number 85558

Rev. 1.6, 06-Apr-04

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